

Available Q2, 1995

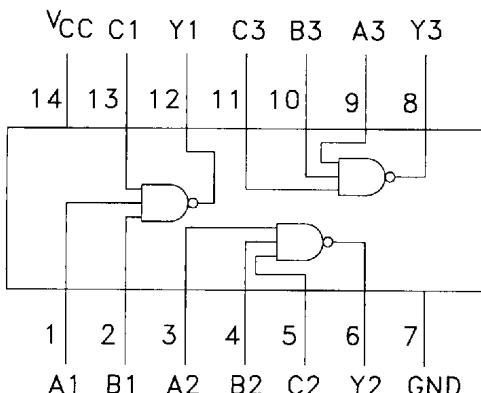
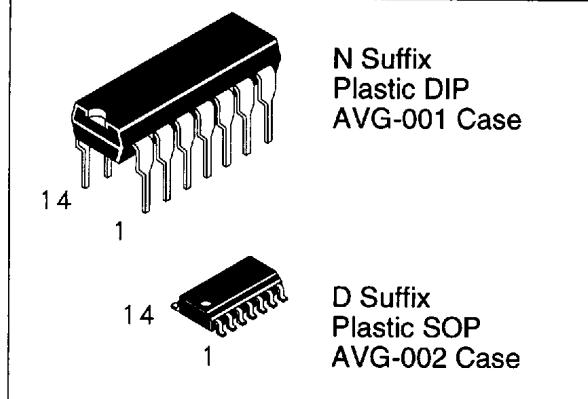
### Triple 3-Input NAND Gate

This device contains three independent gates, each of which performs the logic NAND function.

- Advanced very high speed CMOS
- Outputs source/sink 24 mA
- Transmission line driving 50 ohms
- ACT has TTL compatible inputs
- AC device operation guaranteed from 2 to 6 volts
- DC & AC Parameters guaranteed over -40 to +85°C

**DV74AC10**

**DV74ACT10**



**TRUTH TABLE**

Inputs			Outputs
A	B	C	Y
L	X	X	H
X	L	X	H
X	X	L	H
H	H	H	L

H=High Logic Level

L=Low Logic Level

X=Don't Care

### ABSOLUTE MAXIMUM RATINGS

Maximum ratings are those values beyond which damage to the device may occur.

Symbol	Parameter	AC10, ACT10	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	- 0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	- 0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	- 0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	± 20	mA
I <sub>OUT</sub>	DC Output Sink/Source Current, per Pin	± 50	mA
I <sub>CC</sub>	DC V <sub>CC</sub> or GND Current per Output Pin	± 50	mA
T <sub>STG</sub>	Storage Temperature	- 65 to +150	°C

### GUARANTEED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V <sub>CC</sub>	Supply Voltage	'AC	2.0	5.0	6.0
		'ACT	4.5	5.0	5.5
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage, (Ref. to GND)	0		V <sub>CC</sub>	V
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 1) 'AC Devices	V <sub>CC</sub> @ 3.0 V		150	ns/V
		V <sub>CC</sub> @ 4.5 V		40	ns/V
		V <sub>CC</sub> @ 5.5 V		25	ns/V

# GUARANTEED OPERATING CONDITION (continued)

Symbol	Parameter	Min	Typ	Max	Unit
tr, tf	Input Rise and Fall Time (Note 2) 'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V		10	ns/V
		V <sub>CC</sub> @ 5.5 V		8.0	ns/V
T <sub>A</sub>	Operating Ambient Temperature Range	-40	25	85	°C
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 5.0 V		4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>CC</sub> = 5.0 V		25	pF

1. V<sub>IN</sub> from 30% to 70% V<sub>CC</sub>

2. V<sub>IN</sub> from 0.8 to 2.0 V

## AC — 10

### DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	AC10			Unit
				TA = +25°C		TA = -40 to +85°C	
				Typ	Guaranteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V
V <sub>IL</sub>	Maximum Low Level Input Voltage	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V
V <sub>OH</sub>	Minimum High Level Output Voltage	I <sub>OUT</sub> = -50 μA	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V
		V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> -12mA I <sub>OH</sub> -24mA -24mA	3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	V
V <sub>OL</sub>	Maximum Low Level Output Voltage	I <sub>OUT</sub> = 50 μA	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V
		V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> 12mA I <sub>OL</sub> 24mA 24mA	3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	V
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		±0.1	±1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		4.0	40	μA

### AC CHARACTERISTICS over full operating conditions

Symbol	Parameter	V <sub>CC</sub> ±10% (V)	AC10				Unit	
			TA = +25°C C <sub>L</sub> = 50 pF		TA = -40°C to +85°C C <sub>L</sub> = 50 pF			
			Min	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	1.5 1.5	9.5 7.0	1.0 1.0	10.5 8.0	ns	
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	1.5 1.5	8.5 6.0	1.0 1.0	10.0 6.5	ns	

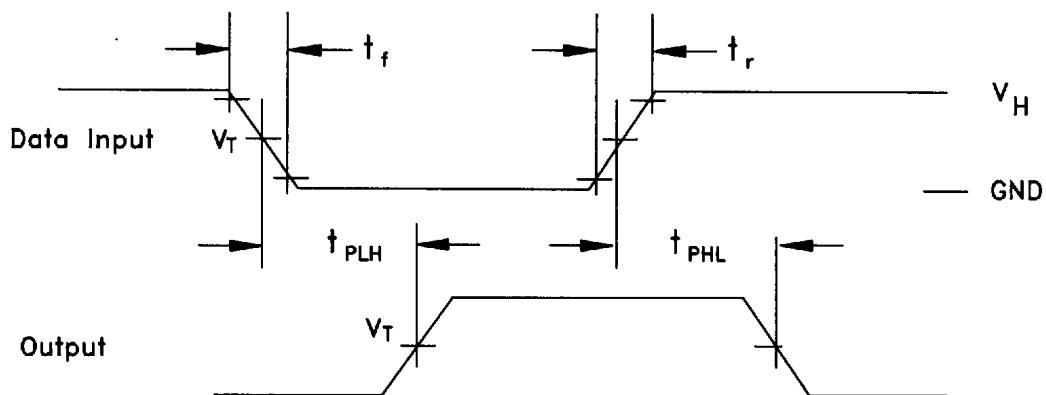
## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Vcc (V)	ACT10			Unit
				TA = +25°C		TA = -40 to +85°C	
				Typ	Guaranteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> – 0.1 V	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V
V <sub>IL</sub>	Maximum Low Level Input Voltage	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> – 0.1 V	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V
V <sub>OH</sub>	Minimum High Level Output Voltage	I <sub>OUT</sub> = -50 μA	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V
		V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> -24mA -24 mA	4.5 5.5		3.86 4.86	3.76 4.76	V
V <sub>OL</sub>	Maximum Low Level Output Voltage	I <sub>OUT</sub> = 50 μA	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V
		V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OL</sub> 24mA 24 mA	4.5 5.5		0.36 0.36	0.44 0.44	V
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		±0.1	±1.0	μA
ΔI <sub>CCT</sub>	Additional Max I <sub>CC</sub> /Input	V <sub>IN</sub> = V <sub>CC</sub> – 2.1 V	5.5	0.6		1.5	mA
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		4.0	40	μA

## AC CHARACTERISTICS over full operating conditions

Symbol	Parameter	V <sub>CC</sub> ±10% (V)	ACT10				Unit	
			TA = +25°C C <sub>L</sub> = 50 pF		TA = -40°C to +85°C C <sub>L</sub> = 50 pF			
			Min	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	5.0	1.0	9.0	1.0	10.0	ns	
t <sub>PHL</sub>	Propagation Delay	5.0	1.0	9.0	1.0	9.5	ns	

## SWITCHING WAVEFORMS



Input and output threshold voltage:  
V<sub>T</sub> = 50% V<sub>CC</sub> for AC; 1.5V for ACT  
V<sub>H</sub> = V<sub>CC</sub> for AC, 3V for ACT